

# **DHG10C600PB**

preliminary

# $V_{RRM} = 600 V$

$$I_{FAV} = 2x$$
 5 A

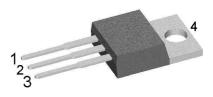
$$t_{rr}$$
 = 35 ns

High Performance Fast Recovery Diode Low Loss and Soft Recovery Common Cathode

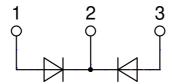
**Sonic Fast Recovery Diode** 

Part number

#### **DHG10C600PB**



Backside: cathode



## Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

## **Applications:**

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

## Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

#### **Disclaimer Notice**

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at <a href="https://www.littelfuse.com/disclaimer-electronics">www.littelfuse.com/disclaimer-electronics</a>.





preliminary

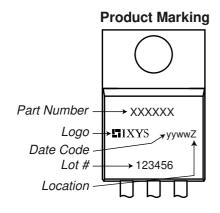
Fast Diode				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V <sub>RSM</sub>	max. non-repetitive reverse blockir	ng voltage	$T_{VJ} = 25^{\circ}C$			600	V
V <sub>RRM</sub>	max. repetitive reverse blocking vo	oltage	$T_{VJ} = 25^{\circ}C$			600	V
IR	reverse current, drain current	$V_R = 600 \text{ V}$	$T_{VJ} = 25^{\circ}C$			10	μΑ
		$V_R = 600 \text{ V}$	$T_{VJ} = 125^{\circ}C$			1	mΑ
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 5 A	$T_{VJ} = 25^{\circ}C$			2.21	V
		$I_F = 10 A$				3.07	٧
		I <sub>F</sub> = 5 A	T <sub>VJ</sub> = 125°C			2.17	V
		$I_F = 10 A$				3.13	٧
I FAV	average forward current	T <sub>C</sub> = 105°C	T <sub>vJ</sub> = 150°C			5	Α
		rectangular d = 0.5					
V <sub>F0</sub>	threshold voltage		$T_{VJ} = 150$ °C			1.14	٧
$\mathbf{r}_{F}$	slope resistance	ss calculation only				185	mΩ
R <sub>thJC</sub>	thermal resistance junction to case	;				3.15	K/W
R <sub>thCH</sub>	thermal resistance case to heatsin	k			0.5		K/W
P <sub>tot</sub>	total power dissipation		$T_C = 25^{\circ}C$			40	W
I <sub>FSM</sub>	max. forward surge current	$t = 10 \text{ ms}$ ; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			40	Α
CJ	junction capacitance	$V_R = 400  \text{V}$ f = 1 MHz	$T_{VJ} = 25^{\circ}C$		3		pF
I <sub>RM</sub>	max. reverse recovery current		$T_{VJ} = 25 ^{\circ}\text{C}$		2		Α
		$I_F = 5 \text{ A}; V_R = 400 \text{ V}$	$T_{VJ} = {}^{\circ}C$		tbd		Α
t <sub>rr</sub>	reverse recovery time	$\begin{cases} I_F = 5 A; V_R = 400 V \\ -di_F / dt = 100 A / \mu s \end{cases}$	$T_{VJ} = 25 ^{\circ}C$		35		ns
	J	1	$T_{VJ} = {}^{\circ}C$		tbd		ns



# DHG10C600PB

preliminary

Package TO-220				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
I <sub>RMS</sub>	RMS current	per terminal 1)			35	Α	
T <sub>VJ</sub>	virtual junction temperature		-55		150	°C	
T <sub>op</sub>	operation temperature		-55		125	°C	
T <sub>stg</sub>	storage temperature		-55		150	°C	
Weight				2		g	
M <sub>D</sub>	mounting torque		0.4		0.6	Nm	
F <sub>c</sub>	mounting force with clip		20		60	Ν	



## Part description

D = Diode

H = Sonic Fast Recovery Diode

G = extreme fast

10 = Current Rating [A]

C = Common Cathode

600 = Reverse Voltage [V] PB = TO-220AB (3)

Orde	ing	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Stand	ard	DHG10C600PB	DHG10C600PB	Tube	50	505294

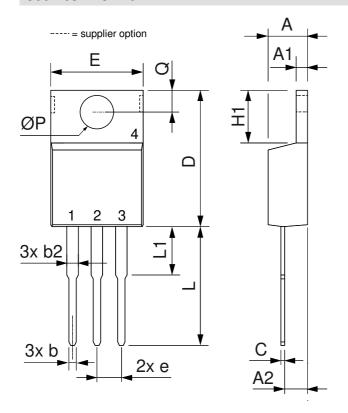
<b>Equivalent Circuits for Simulation</b>			* on die level	$T_{VJ} = 150^{\circ}C$
$I \rightarrow V_0$	)— <u>R</u> o	Fast Diode		
V <sub>0 max</sub>	threshold voltage	1.14		V
R <sub>0 max</sub>	slope resistance *	182		mΩ



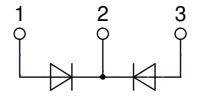


preliminary

# Outlines TO-220



Dim.	Millimeter		Inches		
	Min.	Max.	Min.	Max.	
Α	4.32	4.82	0.170	0.190	
A1	1.14	1.39	0.045	0.055	
A2	2.29	2.79	0.090	0.110	
b	0.64	1.01	0.025	0.040	
b2	1.15	1.65	0.045	0.065	
С	0.35	0.56	0.014	0.022	
D	14.73	16.00	0.580	0.630	
E	9.91	10.66	0.390	0.420	
е	2.54	BSC	0.100	BSC	
H1	5.85	6.85	0.230	0.270	
L	12.70	13.97	0.500	0.550	
L1	2.79	5.84	0.110	0.230	
ØP	3.54	4.08	0.139	0.161	
Q	2.54	3.18	0.100	0.125	



# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

IXYS:

DHG10C600PB